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Silicon Die Self-alignment on a Wafer: Stable and Unstable Modes

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Abstract: 3D integration is the key to advanced microelectronic systems. Die-to-wafer assembly is a necessary step to reach full integration. Self-assembly methods are promising due to their parallel aspect which overcomes the main difficulties of the current techniques. The aim of this work is the understanding of the mechanisms of self-alignment with an evaporating droplet technique and the investigation the stable and unstable modes. Using the Surface Evolver software, we analyze the causes for misalignments of the system and their evolution. *Copyright* © 2010 IFSA.

Keywords: Self-alignment, Misalignment, Silicon die, Surface energy minimization

1. Introduction

Integration of components on a wafer is needed to obtain fast and reliable packaging [1]. Selfassembly methods are promising due to their parallel aspect which overcomes the main difficulties of the current techniques. It is expected that such methods could yield a higher assembly throughput rate and a higher alignment precision than conventional methods like robotics [2, 3]. In this work we focus on the self-alignment of dies using droplets deposited on specific hydrophilic locations on the wafer. Capillary forces are used to align the die and evaporation of the liquid droplet eventually leads to contact and direct bonding of the die on the substrate [4-8]. This technique theoretically allows for self-alignment and assembly without any intermediate layer (Fig. 1). The bonding strength is high enough so that the assembly can handle post processing, such as thinning down or through-via etching for interconnects.



Fig. 1. Principle of die self-alignment: (a) sketch of the droplet and the die; (b) sketch of the die before and after evaporation; (c) view of aligned dies on a wafer [9].

In a first step, the die is gently dropped on a water droplet sitting on a square hydrophilic patch patterned on the wafer surface. At this point, three physical phenomena govern the die motion: (i) water-air interfacial forces that are expected to bring the die in an aligned position above its planned final location on the wafer, (ii) evaporation of the water that progressively moves the die towards the wafer surface, (iii) gravitational forces linked to the weight of the die and the liquid.

Experiments have been conducted with an experimental setup composed of dies on top of water droplets deposited with the help of a syringe on delimited regions of a substrate (Fig. 1). The die is a square plate of 5 mm x 5 mm, its thickness is 725 μ m, and its weight is less than 45 mg. The silicon surface of the die is super hydrophilic, with a water contact angle of the order of 2-3°. The substrate binding zone has the same size and is hydrophilically treated and surrounded by hydrophobic regions (Fig. 2). Note that the dimensional tolerance of die and patch conditions the alignment precision. Fabrication efforts are conducted to reach a dimensional tolerance less than 1 μ m for the die as well as for the patch on the wafer. However in the numerical model, an ideal case is examined and the dimensional tolerance is set to zero.

The first experimental results have shown that good angular alignment is achieved, but a slight translational misalignment of the order of 10 to 20 μ m can occur (Fig. 3). In previous publications [10, 11], the possible reasons for misalignments have been experimentally investigated. We analyze here the self-alignment mechanism of the die on the wafer with the help of numerical simulation.



Fig. 2. View of the boundary between the hydrophilic and hydrophobic regions; the bonding zone has been functionalized by oxygen plasma.



Fig. 3. Dicing marks (left) permit control of the alignment: a good angular alignment is reached, but a slight x-y shift may occur.

More specifically, our goal is to understand the details of the mechanisms of self-alignment and investigate the stable and unstable displacement modes. Using the characteristic times for capillarity, inertia and evaporation, we show that self-alignment mechanism is governed by the capillary force exerted by the liquid-air interface. Hence the Surface Evolver software is well adapted for the analysis and to the prediction of the response of the system to misalignments and its evolution, e.g. whether the die re-aligns [12, 13]. Let us recall that Surface Evolver software uses a surface integral method which only requires the meshing of the surface. It numerically determines the static—or quasi-static—location of an interface submitted to mechanical constraints by an energy minimization approach. Note that fluid dynamics effects are not taken into account with this method. Typically in an Evolver calculation, a meshing of an arbitrary surface containing the liquid volume - here a parallelepiped surface—is initially realized, and the surface evolves to reach an equilibrium state.

2. Physical Analysis

Let us first compare the characteristic times of the different mechanisms acting on the die: capillarity, inertia and evaporation. The Tomotika time - or capillary time - is the time taken by a distorted liquidair interface to regain its equilibrium shape against the action of viscosity [14]. It is given by the ratio

$$au_{capillary} = rac{\eta R}{\gamma},$$

where η is the fluid viscosity, *R* a characteristic dimension of the interface (here the vertical gap *h*), and γ the surface tension. Using a water viscosity value of $\eta = 10^{-3}$ Pa.s, a vertical gap $h = 20 \mu \text{m}$ and a surface tension between water and air $\gamma = 72.10^{-3}$ N/m, we obtain $\tau_{capillary} < 10^{-6}$ seconds. On the other hand, the inertial time is given by

$$\tau_{inertia} = d/V$$
,

where *d* is the global displacement and *V* the average velocity. *V* is obtained from the experiment using $d\sim10-100 \ \mu\text{m}$ and $V\sim0.1 \ \text{mm/s}$. The inertial time is then of the order of 0.1 to 1 seconds. Finally evaporation has a characteristic time of the order of

$$\tau_{evap} \approx \frac{4 h L}{D},$$

where *h* is the vertical gap, *L* the dimension of the chip and *D* the diffusion coefficient. Using the typical values of $h=20 \ \mu\text{m}$, $L=5 \ \text{mm}$ and $D=10^{-9} \ \text{m/s}^2$, the evaporation time is $\tau_{evap} \approx 400$ seconds. This value is in agreement with the experiments showing complete evaporation after 4 to 5 minutes. Hence we have $\tau_{capillary} \ll \tau_{inertia} \ll \tau_{evap}$. The displacement of the die is then governed by capillary forces linked to the minimization of the liquid surface area under the constraints exerted by the liquid and die weight [15, 16]. The surface energy of the droplet is given by

$$E_{T} = \gamma_{WA} S_{WA} + \gamma_{SW} S_{SW} + \gamma_{DW} S_{DW}, \qquad (1)$$

where S_{WA} , S_{SW} , S_{DW} are respectively the surface areas of the water-air interface, substrate-water interface and die-water interface, and γ_{WA} , γ_{SW} , γ_{DW} the surface tensions between water and air, substrate and water, and die and water. We make the simplifying hypothesis that the droplet is pinned on the die edges on one side, and on the contour line of the hydrophilic patch on the other side. Hence, the contact angles do not intervene and the energy to be minimized is only that of the water-air interface $E = \gamma_{WA} S_{WA}(x, y, z, \theta, \alpha, \phi, P, \gamma)$ where x, y, z are the coordinates of the mass center of the plate, θ, α, ϕ the directing angles of the plate, P the weight of the die and γ the surface tension between water and air. We use the Surface Evolver numerical software to follow the displacement of the die towards its stable position minimizing the surface energy, which, in this precise case, is the same as minimizing the interfacial area.

Four different displacement modes can be identified (Fig. 4): (1) the lift corresponding to a vertical motion of the plate, (2) the twist corresponding to a rotation of the plate in the horizontal plane, (3) the shift which is a horizontal translation of the plate, and (4) the tilt or roll which are respectively a rotation around the horizontal y-axis or x-axis (Fig. 4).

We investigate successively these four modes and check if each of these modes brings back the die to an aligned position.

2.1. First Mode: Horizontal Displacement (Shift)

Let us denote γ the surface tension, *L* the side length of the die, *S* the interfacial area, and *V*_l the liquid volume. The first displacement mode corresponds to a horizontal shift of the die (Fig. 5). It is obvious that the interfacial area is larger after a shift. Consequently the capillary forces will act to reduce the interfacial area by bringing back the die into alignment.



Fig. 4. The four different modes (and possible reasons for misalignment): lift, twist, shift and tilt.



Fig. 5. (a) After a horizontal displacement, the die is pulled back to alignment by capillary forces; (b) Evolver calculation of the restoring force.

A calculation with Surface Evolver shows that strong capillary forces pull back the die into alignment (Fig. 5). The force along the horizontal direction x is given by

$$F_{x} = -\frac{\partial(\gamma S)}{\partial x}.$$
 (2)

Fig. 6 shows the values of the restoring force for different liquid gaps. In the case of small shifts, this force is larger for small gaps because of the larger relative change of interfacial surface area.

This behavior can be checked against an approximate model where the interfaces would be planar (which is not exactly true). Under this assumption, it can be easily shown (Appendix 1) that the liquidair surface energy is approximately

$$\Delta E \approx 2\gamma h L \left(1 + \sqrt{1 + \left(\frac{x}{h}\right)^2} \right), \tag{3}$$

where *x* is the horizontal shift and the capillary force is

$$F_{x} \approx -2\gamma L \frac{1}{\sqrt{1 + \left(\frac{h}{x}\right)^{2}}}.$$
(4)

This formula compares well with Evolver results, as shown in Fig. 7.



Fig. 6. Restoring force vs. shift for different values of the droplet volume.



Fig. 7. Comparison between approximate analytical model (plain line) and Evolver (dots). Left: interfacial energy; right: restoring force.

The energy curves in figure 7 show that the real interfacial area at zero shift—calculated with Evolver—is a little smaller than that corresponding to 4 planar interfaces (S = 4 h L). This is linked to the shape of the interface, corresponding to a minimal surface area. For very small shifts, $x/h \ll 1$ and $F_x \approx -2\gamma L \frac{x}{h}$: the restoring force is a linear function of the shift; for large shifts $x/h \gg 1$, $F_x \approx -2\gamma L and$ the restoring force is constant. An important observation stemming from equation (4) and from Evolver results is that the restoring force is larger for small vertical gaps h.

2.2. Second Mode: Twist

A twist is a rotation around the vertical z-axis. In this case too, a twist increases the interfacial area, and the die is pulled back to alignment, as shown in Fig. 8. As for the shift, we have approached the problem by using Surface Evolver and comparing the results to an approximate analytical model where the interfaces—initially planar—are twisted progressively (Appendix 2).



Fig. 8. Die realigns after an initial twist.

Let us recall that the torque on the die is given by

$$T = -\frac{\partial(\gamma S)}{\partial \theta}.$$
(5)

Interfacial energy and torque are plotted in Fig. 9 as functions of the twist angle for three different liquid heights (100, 200 and 500 μ m).



Fig. 9. Energy (left) and torque (right) as functions of the twist angle, for three values of the gap. Dotted lines are Surface Evolver results and plain lines correspond to the analytical model.

The surface energy is obviously larger for larger gap; also the derivative with respect to the twist angle is larger for small gaps, i.e. the variation of surface area with the twist angle is larger in the case of

small gaps. Hence, the torque is larger for smaller liquid volumes. The analytical model produces a torque value given by

$$T \approx \gamma L^{2} \left[\frac{a}{\sqrt{1+a^{2}}} + \frac{1}{\left(a+\sqrt{1+a^{2}}\right)} \left(\frac{1}{a} + \frac{1}{\sqrt{1+a^{2}}} \right) - \frac{\ln\left(a+\sqrt{1+a^{2}}\right)}{a^{2}} \right]$$
(6)

with $a = L\theta/(2h)$. For small twists, the analytical model compares well with Evolver, but not for large twists. In this latter case, the interfacial surface is considerably affected by surface tension forces and the hypothesis used by the analytical model is not physical. In such a case Evolver numerical approach is essential to predict the real shape of the interfaces and consequently deduce the values of the torque.

2.3. Third Mode: Vertical Displacement (Lift)

Because the vertical location of the die is a balance between gravity and capillary forces, it is expected that there is only one stable height for the die. This height depends on the liquid volume and die weight. This analysis rejoins the work of Suzuki [17]. This is confirmed by the numerical simulation (Fig. 10).



Fig. 10. Die regains its stable position after a lift. Top: after an initial lift; bottom: after an initial compression.

2.4. Fourth Mode: Tilt (or Roll)

We will call tilt a rotation around the y-axis and roll a rotation around the x-axis. Basically twist and roll share the same behavior. Besides, in our case where the chip has a square shape, tilt and roll are exactly identical. Tilt is a complex phenomenon because the variation of the interfacial area is more difficult to intuitively predict. If we make the very simple calculation depicted in Fig. 11, we deduce that the problem is indeterminate. For the same volume of the same liquid, assuming the simplest form of interfaces, the surface energy in a flat configuration is

$$E = \gamma S = \gamma \left(4Lh\right) = \gamma \left(4\frac{V_l}{L}\right),\tag{7}$$

where V_l is the liquid volume. In a dihedral morphology, the surface energy is

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$$E = \gamma S = \gamma \left[2 \left(\frac{\alpha L^2}{2} \right) + \alpha L^2 \right] = \gamma \left(4 \frac{V_l}{L} \right).$$
(8)

Hence, it is the distortion of the interfaces that can make the difference and pinpoint the stable position. It is a second order problem. This remark leads to serious complications: on a numerical standpoint, the meshing of the surface should be sufficiently fine to produce a precise value of the energy. In return, the computation time is long. From a physical standpoint, the role of the parameters - like the weight of the die, or the surface tension of the liquid - is difficult to predict.



Fig. 11. Two morphologies of the liquid having the same surface energy.

The numerical model shows that the dihedral position (b in Fig. 11) is the stable position whatever the initial depth of the liquid gap (Fig. 12).



Fig. 12. Die tilts to form a dihedral: (a) and (b) large liquid volume; (c) and (d) small liquid volume.

The slightly smaller interfacial area for the dihedral morphology is due to small distortions of the interface in the die corners and along the die sides. The interface is concave in the first regions, and convex in the others (Fig. 13). Parallel die-wafer morphology has 4 concave and 4 convex distortions, whereas the dihedral die-wafer morphology has only 2 concave and 3 convex distortions.



Fig. 13. Bulging out/in shape of the interface in the two cases: left, parallel plates; right, corner.

2.5. Coupled Modes

From the previous analysis, it is expected that only coupled modes including roll and tilt will be unstable. This can be verified with Surface Evolver (Fig. 14). This software calculates an equilibrium state and does not compute a dynamic motion. However, the iteration speed indicates a relative facility or difficulty of displacement. For a tilt and roll initial displacement (Fig. 14.a), there is first a slow motion of the plate that accelerates until one corner and then an edge of the chip contacts the substrate. After that, the motion is slow to form a complete dihedral. In the case of an initial tilt and twist (Fig. 14.b), the twist vanishes quickly (it is a stable mode) but the tilt slowly increases. Finally, for an initial shift and twist—which are two stable modes—the shift vanishes first, then the twist (Fig. 14.c).



Fig. 14. Coupled modes: (a): tilt and roll; (b) tilt and twist; (c) shift and twist. The only unstable coupling must include a tilt and/or roll; the other modes are automatically corrected by the capillary forces.

3. Discussion and Conclusions

Of all the four modes, only the tilt (roll) is slightly unstable. However, this latter mode does not disrupt necessarily the die alignment. First, if the dihedral is well formed, as shown in Fig. 13, the evaporation will bring the die in perfect alignment. Second, the tilt-motion mode is slow if the die weight is small; evaporation might proceed before the dihedral is completely formed. This point is still under investigation.

Note that the weight of the die (and the volume of the droplet) is an important parameter at this stage. Let us take the extreme case of a large droplet and a heavy die (values that are out of the range of our problem). It can be shown that the die slides on the droplet surface (Fig. 15). This has two consequences: first, a perfect aligned dihedral might not be formed; second, liquid can be drained out of the hydrophilic region on the wafer. Each phenomenon leads to misalignment. Of course, in the real case the droplet is much smaller and the die is very light (less than 0.1 grams); nevertheless that could be the reason for the observed small misalignments.



Fig. 15. Die might slides on the droplet surface after a tilt, depending on its weight.

De-pinning might also be a problem for alignment: if the liquid overflows on the hydrophobic surface, the alignment has no reasons to be good. Curiously, de-pinning has the property to be stable to tilt, allowing the die to regain horizontality, as shown in Fig. 16.

In conclusion, die self-alignment using patterning and droplet evaporation is a promising technique (Fig. 17). Shift, lift and twist misalignments are prevented by the capillary forces. Tilt or roll misalignment is slightly unstable, but, under the condition that the die is light enough and the liquid volume small, the die will eventually form a receding dihedral aligned with the wafer. A strong hydrophilic-hydrophobic contrast is needed to prevent liquid overflow.



Fig. 16. Image of the liquid droplet overflowing outside the super-hydrophilic patch area (contact angle on the patch 3°, and 60° outside on the wafer) after a too brutal deposition of the die. The die comes back into horizontal position (a and b). This expansion allows the die regain horizontality (b). However alignment is lost (c).



Fig. 17. Dies aligned on a wafer.

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Appendix 1: Shift Energy and Restoring Force

In this appendix, planar interfaces are assumed. The shift is then sketched in the Fig. A.1.



Fig. A.1. Sketch of the shift: left, at alignment; right, after a shift.

The volume of the liquid is then

$$V_l = h L^2 . (A1.1)$$

And the interfacial area at alignment is given by

$$S_1 = \frac{4V_l}{L} \,. \tag{A1.2}$$

With the same assumption of planar interfaces, the interfacial area with a shift x is

$$S_{2} = \frac{2V_{l}}{L} \left(1 + \sqrt{1 + \left(\frac{x}{h}\right)^{2}} \right) = 2h L \left(1 + \sqrt{1 + \left(\frac{x}{h}\right)^{2}} \right).$$
(A1.3)

Remark that when $x \rightarrow 0$, $E \rightarrow 4 h L$. The surface energy difference $\Delta E = \gamma (E_2 - E_1)$ is

$$\Delta E = \gamma \left(\frac{2V_l}{L}\right) \left(\sqrt{1 + \left(\frac{x}{h}\right)^2} - 1\right).$$
(A1.4)

The restoring force is then

$$F_x \approx -2\gamma L \frac{1}{\sqrt{1 + \left(\frac{h}{x}\right)^2}} \,. \tag{A1.5}$$

Appendix 2: Twist Energy and Restoring Torque

In this appendix, the four interfaces are supposed to be planar at alignment, having square angles between each other. Recall that a twist around axis *z* and angle θ corresponds to the rotation matrix

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$$R = \begin{pmatrix} \cos\theta & -\sin\theta & 0\\ \sin\theta & \cos\theta & 0\\ 0 & 0 & 1 \end{pmatrix}.$$
 (A2.1)

The twist can be sketch as in Fig. A.2.



Fig. A.2. Sketch of the twist. The point M is describing AB while M' is describing A'B'. Note that s=L/2.

In order to obtain a twist of angle θ , we suppose that the interfaces are progressively twisted from z=0 to z=h, with an angle of $\frac{z}{h}\theta$. For a fixed *y*, the current point M (*s*,*y*, θ) describes a spiral curve defined by

$$\widetilde{M} = \begin{pmatrix} s \cos\left(\frac{z}{h}\theta\right) - y\sin\left(\frac{z}{h}\theta\right) \\ s \sin\left(\frac{z}{h}\theta\right) + y\cos\left(\frac{z}{h}\theta\right) \\ z \end{pmatrix}.$$
(A2.2)

Let us consider the parametric function f such as

$$f: [-s,s]x[0,h] \to \Re^3 \quad such \ as \quad (y,z) \to \begin{pmatrix} s \ \cos\left(\frac{z}{h}\theta\right) - y\sin\left(\frac{z}{h}\theta\right) \\ s \ \sin\left(\frac{z}{h}\theta\right) + y\cos\left(\frac{z}{h}\theta\right) \\ z \end{pmatrix}$$
(A2.3)

This function produces the coordinates of \widetilde{M} . The infinitesimal surface ds is given by

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$$ds = \left\| \frac{\partial f}{\partial y} \times \frac{\partial f}{\partial z} \right\| dy dz.$$
 (A2.4)

Using the calculated values

$$\frac{\partial f}{\partial y} = \begin{cases} -\sin\left(\frac{z}{h}\theta\right) \\ \cos\left(\frac{z}{h}\theta\right) \\ 0 \end{cases}$$

$$\frac{\partial f}{\partial z} = \begin{cases} -\frac{\theta}{h} \left[s \sin\left(\frac{z}{h}\theta\right) + y \cos\left(\frac{z}{h}\theta\right)\right] \\ \frac{\theta}{h} \left[s \cos\left(\frac{z}{h}\theta\right) - y \sin\left(\frac{z}{h}\theta\right)\right] \\ 1 \end{cases}$$
(A2.5)

the vector product $\frac{\partial f}{\partial y} \times \frac{\partial f}{\partial z}$ is then

$$\frac{\partial f}{\partial y} \times \frac{\partial f}{\partial z} = \begin{cases} \cos\left(\frac{z}{h}\theta\right) \\ \sin\left(\frac{z}{h}\theta\right) \\ \frac{\theta}{h} \left[\left(-\sin\left(\frac{z}{h}\theta\right)\right) \left(s\cos\left(\frac{z}{h}\theta\right) - y\sin\left(\frac{z}{h}\theta\right)\right) + \left(\cos\left(\frac{z}{h}\theta\right)\right) \left(s\sin\left(\frac{z}{h}\theta\right) + y\cos\left(\frac{z}{h}\theta\right)\right) \right] \end{cases}$$

which can be simplified to

$$\frac{\partial f}{\partial y} \times \frac{\partial f}{\partial z} = \begin{cases} \cos\left(\frac{z}{h}\theta\right) \\ \sin\left(\frac{z}{h}\theta\right) \\ \frac{\theta}{h}y \end{cases}$$
(A2.6)

The infinitesimal surface ds is finally

$$ds = \left\| \frac{\partial f}{\partial y} \times \frac{\partial f}{\partial z} \right\| dy \, dz = \sqrt{1 + \left(\frac{y}{h}\theta\right)^2} \, dy \, dz \tag{A2.7}$$

and the interfacial area (for one interface) is

$$A = \int_{z=0}^{z=h} \int_{y=-s}^{y=s} \sqrt{1 + \left(\frac{y}{h}\theta\right)^2} \, dy \, dz = h \int_{y=-s}^{y=s} \sqrt{1 + \left(\frac{y}{h}\theta\right)^2} \, dy = \theta \int_{y=-s}^{y=s} \sqrt{\left(\frac{h}{\theta}\right)^2 + y^2} \, dy \quad .$$

Using the table for irrotational functions integrals [18], we find a total interfacial energy of

$$E = 4\gamma \left[s h \sqrt{1+a^2} + \frac{h^2}{\theta} \ln \left(a + \sqrt{1+a^2} \right) \right], \qquad (A2.8)$$

where $a = \frac{s\theta}{h}$. Note that when $\theta \rightarrow 0$, $a \rightarrow 0$ and $E \rightarrow E = 4\gamma L h$. The torque *T* is given by the derivative of the energy with respect to the angle θ

$$T = 4\gamma s^{2} \left[\frac{a}{\sqrt{1+a^{2}}} + \frac{1}{\left(a+\sqrt{1+a^{2}}\right)} \left(\frac{1}{a} + \frac{1}{\sqrt{1+a^{2}}} \right) - \frac{\ln\left(a+\sqrt{1+a^{2}}\right)}{a^{2}} \right].$$
 (A2.9)

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